TOSHIBA

TOSHIBA SCHOTTKY BARRIER RECTIFIER STACK SCHOTTKY BARRIER TYPE

16FWJ2C42

HIGH SPEED RECTIFIER APPLICATIONS

Repetitive Peak Reverse Voltage : V_{RRM}=30V, 40V

• Average Output Rectified Current: IO=16A

• Low Peak Forward Voltage : V_{FM}=0.55V

MAXIMUM RATINGS

CHARACTERIS	SYMBOL	RATING	UNIT			
Repetitive Peak	16FWJ2C42	Vanas	30	V		
Reverse Voltage	16GWJ2C42	$V_{ m RRM}$	40			
Average Output Rectific (Tc=110°C)	IO	16	A			
Peak One Cycle Surge	I _{FSM}	160 (50Hz)	A			
Current (Sin Wave, Ta		192 (60Hz)				
Junction Temperature	T_{j}	-40~125	°C			
Storage Temperature R	$\mathrm{T_{stg}}$	-40~150	°C			
Screw Torque	_	0.8	N⋅m			

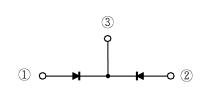
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

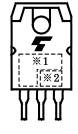
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage (Note 1)	$v_{ m FM}$	$I_{\text{FM}} = 8.0 \text{A}$	_	_	0.55	v
Repetitive Peak Reverse Current (Note 1)	I_{RRM}	V _{RRM} =Rated	_	_	15	mA
Junction Capacitance (Note 1)	$C_{ m j}$	$V_R = 10V, f = 1.0MHz$	360	_	_	рF
Thermal Resistance	R _{th (j-c)}	DC Total, Junction to Case	_	_	1.2	°C/W

(Note 1) A value of one cell.

POLARITY

MARKING



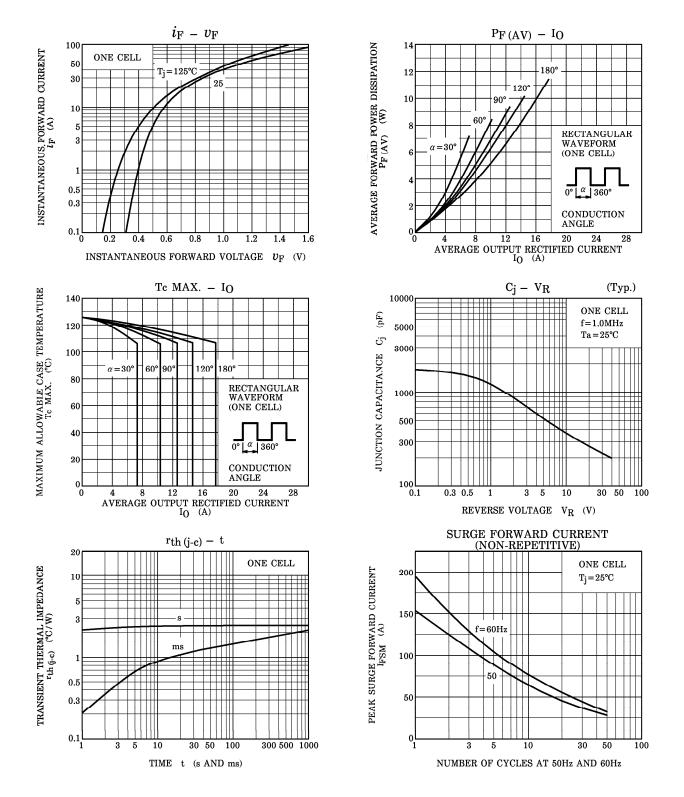


%1	TYPE	16FWJ2C42, 16GWJ2C42
*2	Lot Nu	mber — Month (Starting from Alphabet A) — Year (Last Number of the Christian Era)

Weight: 4.85g

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